8-bit parallel-in/serial out shift register Rev. 3 — 23 April 2020

**Product data sheet** 

### 1. General description

The 74HC165-Q100; 74HCT165-Q100 are 8-bit serial or parallel-in/serial-out shift registers. The device features a serial data input (DS), eight parallel data inputs (D0 to D7) and two complementary serial outputs (Q7 and Q7). When the parallel load input (PL) is LOW the data from D0 to D7 is loaded into the shift register asynchronously. When PL is HIGH data enters the register serially at DS. When the clock enable input ( $\overline{CE}$ ) is LOW data is shifted on the LOW-to-HIGH transitions of the CP input. A HIGH on  $\overline{CE}$  will disable the CP input. Inputs are overvoltage tolerant to 15 V. This enables the device to be used in HIGH-to-LOW level shifting applications.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

### 2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
  Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Asynchronous 8-bit parallel load
- Synchronous serial input
- Complies with JEDEC standard no. 7A
- Input levels:
  - For 74HC165-Q100: CMOS level
  - For 74HCT165-Q100: TTL level
- ESD protection:
  - MIL-STD-883, method 3015 exceeds 2000 V
  - HBM JESD22-A114F exceeds 2000 V
  - MM JESD22-A115-A exceeds 200 V (C = 200 pF, R = 0 Ω)
- DHVQFN package with Side-Wettable Flanks enabling Automatic Optical Inspection (AOI) of solder joints

#### 3. Applications

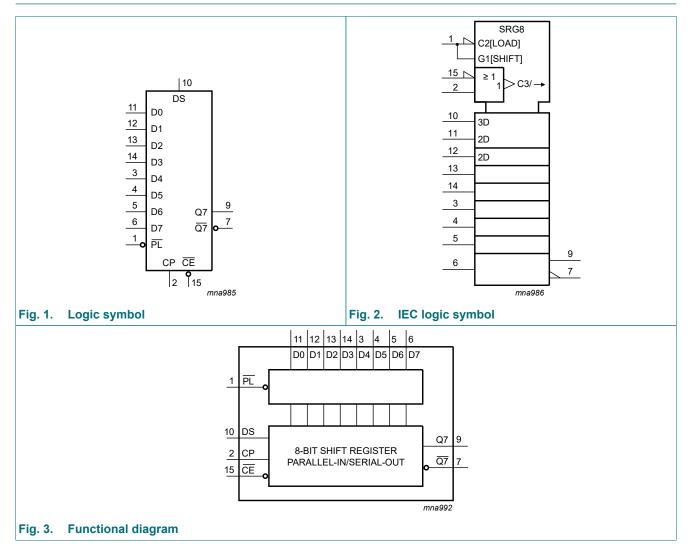
Parallel-to-serial data conversion



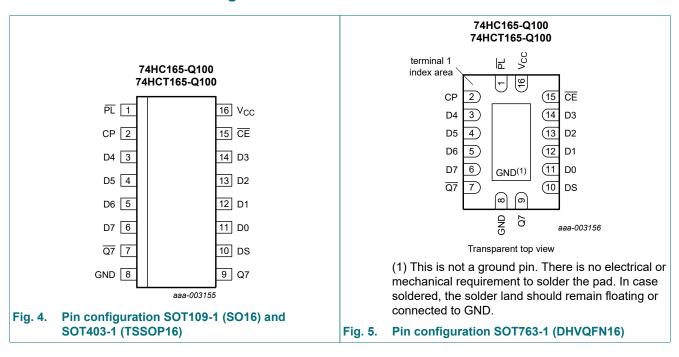
### 4. Ordering information

Type number	Package										
	Temperature range	Name	Description	Version							
74HC165D-Q100	-40 °C to +125 °C	SO16	plastic small outline package; 16 leads;	SOT109-1							
74HCT165D-Q100	-		body width 3.9 mm								
74HC165PW-Q100	-40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads;	SOT403-1							
74HCT165PW-Q100	-		body width 4.4 mm								
74HC165BQ-Q100	-40 °C to +125 °C	DHVQFN16	1 1	SOT763-1							
74HCT165BQ-Q100	1		very thin quad flat package; no leads; 16 terminals; body 2.5 × 3.5 × 0.85 mm								

### 5. Functional diagram



### 6. Pinning information



#### 6.1. Pinning

### 6.2. Pin description

Symbol	Pin	Description							
PL	1	asynchronous parallel load input (active LOW)							
СР	2	clock input (LOW-to-HIGH edge-triggered)							
<u>Q7</u>	7	complementary output from the last stage							
GND	8	ground (0 V)							
Q7	9	serial output from the last stage							
DS	10	serial data input							
D0 to D7	11, 12, 13, 14, 3, 4, 5, 6	parallel data inputs (also referred to as Dn)							
CE	15	clock enable input (active LOW)							
V <sub>CC</sub>	16	positive supply voltage							

### 7. Functional description

#### Table 3. Function table

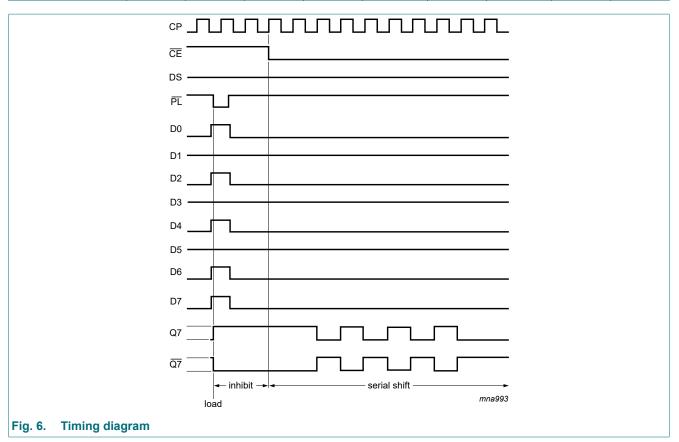
H = HIGH voltage level; h = HIGH voltage level one set-up time prior to the LOW-to-HIGH clock transition;

L = LOW voltage level; I = LOW voltage level one set-up time prior to the LOW-to-HIGH clock transition;

*q* = state of the referenced output one set-up time prior to the LOW-to-HIGH clock transition;

 $X = don't care; \uparrow = LOW-to-HIGH clock transition.$ 

Operating modes	Inputs				Qn reg	isters	Outpu	Outputs	
	PL	CE	СР	DS	D0 to D7	Q0	Q1 to Q6	Q7	<b>Q7</b>
parallel load	L	Х	Х	Х	L	L	L to L	L	Н
	L	Х	Х	Х	Н	Н	H to H	Н	L
serial shift	Н	L	1	I	Х	L	q0 to q5	q6	<u>q6</u>
	Н	L	1	h	Х	Н	q0 to q5	q6	<u>q6</u>
	Н	1	L	I	Х	L	q0 to q5	q6	<u>q6</u>
	Н	1	L	h	Х	Н	q0 to q5	q6	<u>q6</u>
hold "do nothing"	Н	Н	Х	Х	Х	q0	q1 to q6	q7	q7
	Н	Х	Н	Х	X	q0	q1 to q6	q7	<del>q7</del>



### 8. Limiting values

#### Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>CC</sub>	supply voltage			-0.5	+7	V
I <sub>IK</sub>	input clamping current	$V_{I}$ < -0.5 V or $V_{I}$ > $V_{CC}$ + 0.5 V	[1]	-	±20	mA
I <sub>OK</sub>	output clamping current	$V_{\rm O}$ < -0.5 V or $V_{\rm O}$ > $V_{\rm CC}$ + 0.5 V	[1]	-	±20	mA
lo	output current	-0.5 V < V <sub>O</sub> < V <sub>CC</sub> + 0.5 V		-	±25	mA
I <sub>CC</sub>	supply current			-	50	mA
I <sub>GND</sub>	ground current			-50	-	mA
T <sub>stg</sub>	storage temperature			-65	+150	°C
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = -40 °C to +125 °C	[2]	-	500	mW

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For SOT109-1 (SO16) package:  $P_{tot}$  derates linearly with 12.4 mW/K above 110 °C.

For SOT403-1 (TSSOP16) package:  $\mathsf{P}_{tot}$  derates linearly with 8.5 mW/K above 91 °C.

For SOT763-1 (DHVQFN16) package:  $P_{tot}$  derates linearly with 11.2 mW/K above 106  $^\circ\text{C}.$ 

### 9. Recommended operating conditions

#### Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions	74	74HC165-Q100			74HCT165-Q100			
			Min	Тур	Max	Min	Тур	Max	-	
V <sub>CC</sub>	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V	
VI	input voltage		0	-	V <sub>CC</sub>	0	-	V <sub>CC</sub>	V	
Vo	output voltage		0	-	V <sub>CC</sub>	0	-	V <sub>CC</sub>	V	
T <sub>amb</sub>	ambient temperature		-40	-	+125	-40	-	+125	°C	
Δt/ΔV	input transition rise and fall rate	V <sub>CC</sub> = 2.0 V	-	-	625	-	-	-	ns/V	
		V <sub>CC</sub> = 4.5 V	-	1.67	139	-	1.67	139	ns/V	
		V <sub>CC</sub> = 6.0 V	-	-	83	-	-	-	ns/V	

### **10. Static characteristics**

#### Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	25 °C			-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Тур	Мах	Min	Мах	Min	Max	
74HC16	5-Q100									
V <sub>IH</sub>	HIGH-level input	V <sub>CC</sub> = 2.0 V	1.5	1.2	-	1.5	-	1.5	-	V
	voltage	V <sub>CC</sub> = 4.5 V	3.15	2.4	-	3.15	-	3.15	-	V
		V <sub>CC</sub> = 6.0 V	4.2	3.2	-	4.2	-	4.2	-	V
V <sub>IL</sub>	LOW-level input	V <sub>CC</sub> = 2.0 V	-	0.8	0.5	-	0.5	-	0.5	V
ľ	voltage	V <sub>CC</sub> = 4.5 V	-	2.1	1.35	-	1.35	-	1.35	V
		V <sub>CC</sub> = 6.0 V	-	2.8	1.8	-	1.8	-	1.8	V

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Symbol	Parameter	Conditions		25 °C			°C to 5 °C	-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Мах	Min	Max	
V <sub>OH</sub>	HIGH-level	$V_{I} = V_{IH} \text{ or } V_{IL}$								
	output voltage	I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 2.0 V	1.9	2.0	-	1.9	-	1.9	-	V
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 4.5 V	4.4	4.5	-	4.4	-	4.4	-	V
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 6.0 V	5.9	6.0	-	5.9	-	5.9	-	V
		I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 4.5 V	3.98	4.32	-	3.84	-	3.7	-	V
		I <sub>O</sub> = -5.2 mA; V <sub>CC</sub> = 6.0 V	5.48	5.81	-	5.34	-	5.2	-	V
V <sub>OL</sub>	LOW-level	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>								
	output voltage	I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 2.0 V	-	0	0.1	-	0.1	-	0.1	V
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 4.5 V	-	0	0.1	-	0.1	-	0.1	V
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 6.0 V	-	0	0.1	-	0.1	-	0.1	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 4.5 V	-	0.15	0.26	-	0.33	-	0.4	V
		I <sub>O</sub> = 5.2 mA; V <sub>CC</sub> = 6.0 V	-	0.16	0.26	-	0.33	-	0.4	V
I <sub>I</sub>	input leakage current	$V_{I} = V_{CC}$ or GND; $V_{CC} = 6.0 V$	-	-	±0.1	-	±1	-	±1	μA
I <sub>CC</sub>	supply current	current $V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 6.0$ V		-	8.0	-	80	-	160	μA
CI	input capacitance		-	3.5	-	-	-	-	-	pF
74HCT1	65-Q100	1			1	1				
V <sub>IH</sub>	HIGH-level input voltage	$V_{CC}$ = 4.5 V to 5.5 V	2.0	1.6	-	2.0	-	2.0	-	V
V <sub>IL</sub>	LOW-level input voltage	$V_{CC}$ = 4.5 V to 5.5 V	-	1.2	0.8	-	0.8	-	0.8	V
V <sub>OH</sub>	HIGH-level	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$								
	output voltage	I <sub>O</sub> = -20 μA	4.4	4.5	-	4.4	-	4.4	-	V
		I <sub>O</sub> = -4.0 mA	3.98	4.32	-	3.84	-	3.7	-	V
V <sub>OL</sub>	LOW-level	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>								
	output voltage	I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 4.5 V	-	0	0.1	-	0.1	-	0.1	V
		I <sub>O</sub> = 5.2 mA; V <sub>CC</sub> = 6.0 V	-	0.16	0.26	-	0.33	-	0.4	V
l <sub>l</sub>	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 V$	-	-	±0.1	-	±1	-	±1	μA
I <sub>CC</sub>	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 6.0$ V	-	-	8.0	-	80	-	160	μA
ΔI <sub>CC</sub>	additional supply current	per input pin; $V_I = V_{CC} - 2.1 V$ ; other inputs at $V_{CC}$ or GND; $V_{CC} = 4.5 V$ to 5.5 V								
		Dn and DS inputs	-	35	126	-	157.5	-	171.5	μA
		CP, CE, and PL inputs	-	65	234	-	292.5	-	318.5	μA
CI	input capacitance		-	3.5	-	-	-	-	-	pF

## **11. Dynamic characteristics**

#### Table 7. Dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V);  $C_L = 50 \text{ pF}$  unless otherwise specified; for test circuit, see Fig. 12

Symbol Pa	Parameter	Conditions		25 °C			°C to 5 °C		°C to 5 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HC16	5-Q100									
t <sub>pd</sub>	propagation	CP or $\overline{CE}$ to Q7, $\overline{Q7}$ ; see <u>Fig. 7</u> [1]								
	delay	V <sub>CC</sub> = 2.0 V	-	52	165	-	205	-	250	ns
		V <sub>CC</sub> = 4.5 V	-	19	33	-	41	-	50	ns
		V <sub>CC</sub> = 6.0 V	-	15	28	-	35	-	43	ns
		V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF	-	16	-	-	-	-	-	ns
		PL to Q7, Q7; see <u>Fig. 8</u>								
		V <sub>CC</sub> = 2.0 V	-	50	165	-	205	-	250	ns
		V <sub>CC</sub> = 4.5 V	-	18	33	-	41	-	50	ns
		V <sub>CC</sub> = 6.0 V	-	14	28	-	35	-	43	ns
		V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF	-	15	-	-	-	-	-	ns
		D7 to Q7, Q7; see <u>Fig. 9</u>								
		V <sub>CC</sub> = 2.0 V	-	36	120	-	150	-	180	ns
		V <sub>CC</sub> = 4.5 V	-	13	24	-	30	-	36	ns
		V <sub>CC</sub> = 6.0 V	-	10	20	-	26	-	31	ns
		V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF	-	11	-	-	-	-	-	ns
t <sub>t</sub>	transition time	Q7, $\overline{Q7}$ output; see Fig. 7 [2]								
		V <sub>CC</sub> = 2.0 V	-	19	75	-	95	-	110	ns
		V <sub>CC</sub> = 4.5 V	-	7	15	-	19	-	22	ns
		V <sub>CC</sub> = 6.0 V	-	6	13	-	16	-	19	ns
t <sub>W</sub>	pulse width	CP input HIGH or LOW; see Fig. 7								
		V <sub>CC</sub> = 2.0 V	80	17	-	100	-	120	-	ns
		V <sub>CC</sub> = 4.5 V	16	6	-	20	-	24	-	ns
		V <sub>CC</sub> = 6.0 V	14	5	-	17	-	20	-	ns
		PL input LOW; see Fig. 8								
		V <sub>CC</sub> = 2.0 V	80	14	-	100	-	120	-	ns
		V <sub>CC</sub> = 4.5 V	16	5	-	20	-	24	-	ns
		V <sub>CC</sub> = 6.0 V	14	4	-	17	-	20	-	ns
t <sub>rec</sub>	recovery time	PL to CP, CE; see Fig. 8								
		V <sub>CC</sub> = 2.0 V	100	22	-	125	-	150	-	ns
		V <sub>CC</sub> = 4.5 V	20	8	-	25	-	30	-	ns
		V <sub>CC</sub> = 6.0 V	17	6	-	21	-	26	-	ns

Symbol	Parameter	Conditions		25 °C			°C to 5 °C	-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	1
t <sub>su</sub>	set-up time	DS to CP, CE; see Fig. 10								
		V <sub>CC</sub> = 2.0 V	80	11	-	100	-	120	-	ns
		V <sub>CC</sub> = 4.5 V	16	4	-	20	-	24	-	ns
		V <sub>CC</sub> = 6.0 V	14	3	-	17	-	20	-	ns
		CE to CP and CP to CE; see Fig. 10								
		V <sub>CC</sub> = 2.0 V	80	17	-	100	-	120	-	ns
		V <sub>CC</sub> = 4.5 V	16	6	-	20	-	24	-	ns
		V <sub>CC</sub> = 6.0 V	14	5	-	17	-	20	-	ns
		Dn to PL; see <u>Fig. 11</u>								
		V <sub>CC</sub> = 2.0 V	80	22	-	100	-	120	-	ns
		V <sub>CC</sub> = 4.5 V	16	8	-	20	-	24	-	ns
		V <sub>CC</sub> = 6.0 V	14	6	-	17	-	20	-	ns
t <sub>h</sub>	hold time	DS to CP, CE and Dn to PL; see Fig. 10								
		V <sub>CC</sub> = 2.0 V	5	2	-	5	-	5	-	ns
		V <sub>CC</sub> = 4.5 V	5	2	-	5	-	5	-	ns
		V <sub>CC</sub> = 6.0 V	5	2	-	5	-	5	-	ns
		CE to CP and CP to CE; see Fig. 10								
		V <sub>CC</sub> = 2.0 V	5	-17	-	5	-	5	-	ns
		V <sub>CC</sub> = 4.5 V	5	-6	-	5	-	5	-	ns
		V <sub>CC</sub> = 6.0 V	5	-5	-	5	-	5	-	ns
f <sub>max</sub>	maximum	CP input; see <u>Fig. 7</u>								
	frequency	V <sub>CC</sub> = 2.0 V	6	17	-	5	-	4	-	MHz
		V <sub>CC</sub> = 4.5 V	30	51	-	24	-	20	-	MHz
		V <sub>CC</sub> = 6.0 V	35	61	-	28	-	24	-	MHz
		V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF	-	56	-	-	-	-	-	MHz
C <sub>PD</sub>	power dissipation capacitance	per package; $V_1$ = GND to $V_{CC}$ [3]	-	35	-	-	-	-	-	pF
74HCT1	65-Q100			I	1	1	1	1	1	1
t <sub>pd</sub>	propagation	$\overline{CE}$ , CP to Q7, $\overline{Q7}$ ; see Fig. 7 [1]								
	delay	V <sub>CC</sub> = 4.5 V	-	17	34	-	43	-	51	ns
		V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF	-	14	-	-	-	-	-	ns
		PL to Q7, Q7; see <u>Fig. 8</u>								
		V <sub>CC</sub> = 4.5 V	-	20	40	-	50	-	60	ns
		V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF	-	17	-	-	-	-	-	ns
		D7 to Q7, Q7; see Fig. 9								
		V <sub>CC</sub> = 4.5 V	-	14	28	-	35	-	42	ns
		V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF	-	11	-	-	-	-	-	ns

#### 8-bit parallel-in/serial out shift register

Symbol	Parameter	Conditions		25 °C			°C to 5 °C	-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	-
t <sub>t</sub>	transition time	Q7, $\overline{\text{Q7}}$ output; see Fig. 7 [2]								
		V <sub>CC</sub> = 4.5 V	-	7	15	-	19	-	22	ns
t <sub>W</sub>	pulse width	CP input; see <u>Fig. 7</u>								
		V <sub>CC</sub> = 4.5 V	16	6	-	20	-	24	-	ns
		PL input; see <u>Fig. 8</u>								
		V <sub>CC</sub> = 4.5 V	20	9	-	25	-	30	-	ns
t <sub>rec</sub>	recovery time	PL to CP, CE; see Fig. 8								
		V <sub>CC</sub> = 4.5 V	20	8	-	25	-	30	-	ns
t <sub>su</sub>	set-up time	DS to CP, CE; see Fig. 10								
		V <sub>CC</sub> = 4.5 V	20	2	-	25	-	30	-	ns
		CE to CP and CP to CE; see Fig. 10								
		V <sub>CC</sub> = 4.5 V	20	7	-	25	-	30	-	ns
		Dn to PL; see <u>Fig. 11</u>								
		V <sub>CC</sub> = 4.5 V	20	10	-	25	-	30	-	ns
t <sub>h</sub>	hold time	DS to CP, CE and Dn to PL; see <u>Fig. 10</u>								
		V <sub>CC</sub> = 4.5 V	7	-1	-	9	-	11	-	ns
		CE to CP and CP to CE; see Fig. 10								
		V <sub>CC</sub> = 4.5 V	0	-7	-	0	-	0	-	ns
f <sub>max</sub>	maximum	CP input; see <u>Fig. 7</u>								
	frequency	V <sub>CC</sub> = 4.5 V	26	44	-	21	-	17	-	MHz
		V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF	-	48	-	-	-	-	-	MHz
C <sub>PD</sub>	power dissipation capacitance	per package; [3] $V_I$ = GND to $V_{CC}$ - 1.5 V	-	35	-	-	-	-	-	pF

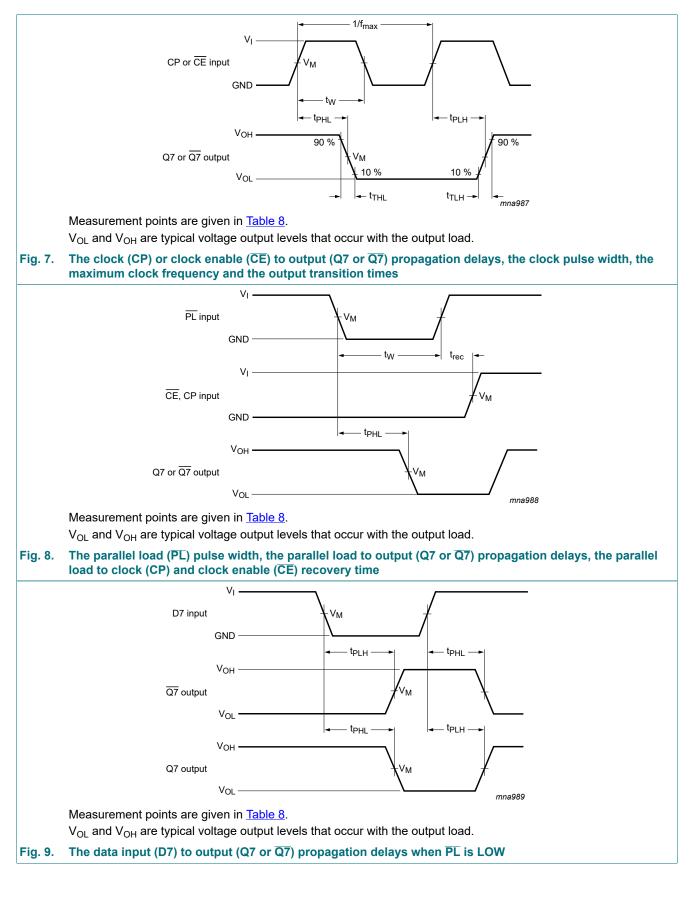
 $f_i$  = input frequency in MHz;

 $f_o$  = output frequency in MHz;

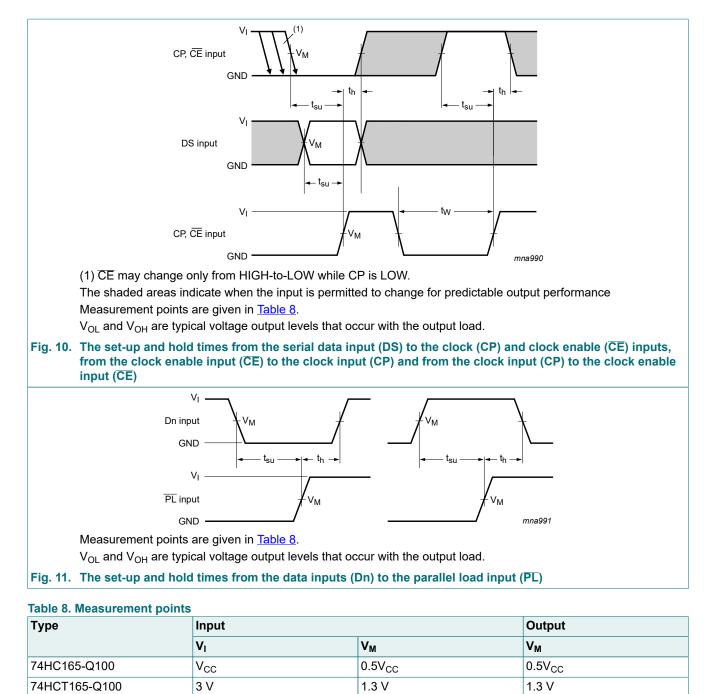
 $\Sigma$  (C<sub>L</sub> × V<sub>CC</sub><sup>2</sup> × f<sub>o</sub>) = sum of outputs;

 $C_L$  = output load capacitance in pF;

 $V_{CC}$  = supply voltage in V.



### 11.1. Waveforms and test circuit



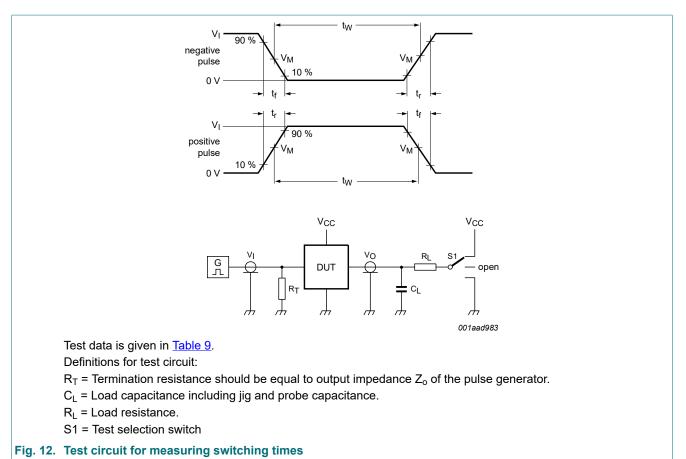
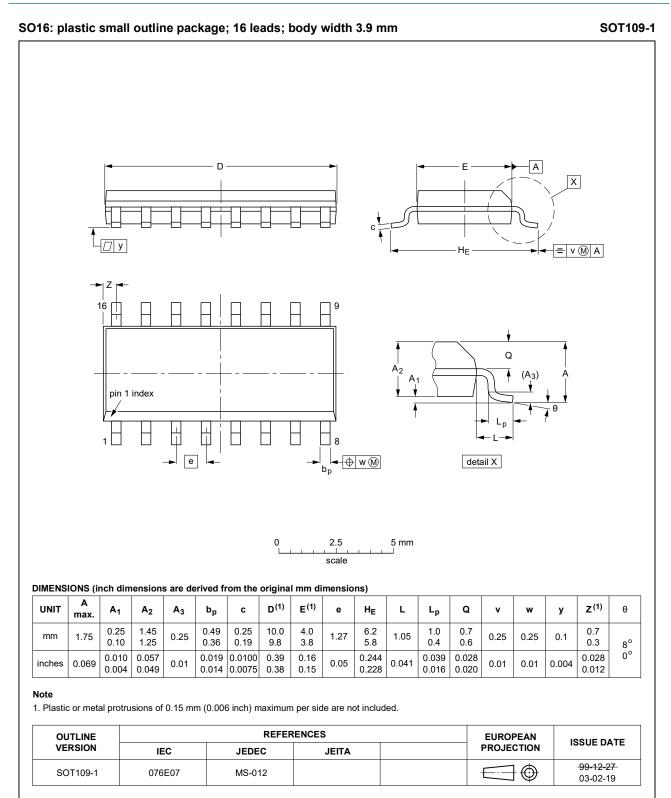


Table 9. Test data											
Туре	Input	Load									
	VI	t <sub>r</sub> , t <sub>f</sub>	CL	RL	t <sub>PHL</sub> , t <sub>PLH</sub>						
74HC165-Q100	V <sub>CC</sub>	6 ns	15 pF, 50 pF	1 kΩ	open						
74HCT165-Q100	3 V	6 ns	15 pF, 50 pF	1 kΩ	open						

### 12. Package outline



#### Fig. 13. Package outline SOT109-1 (SO16)

74HC\_HCT165\_Q100

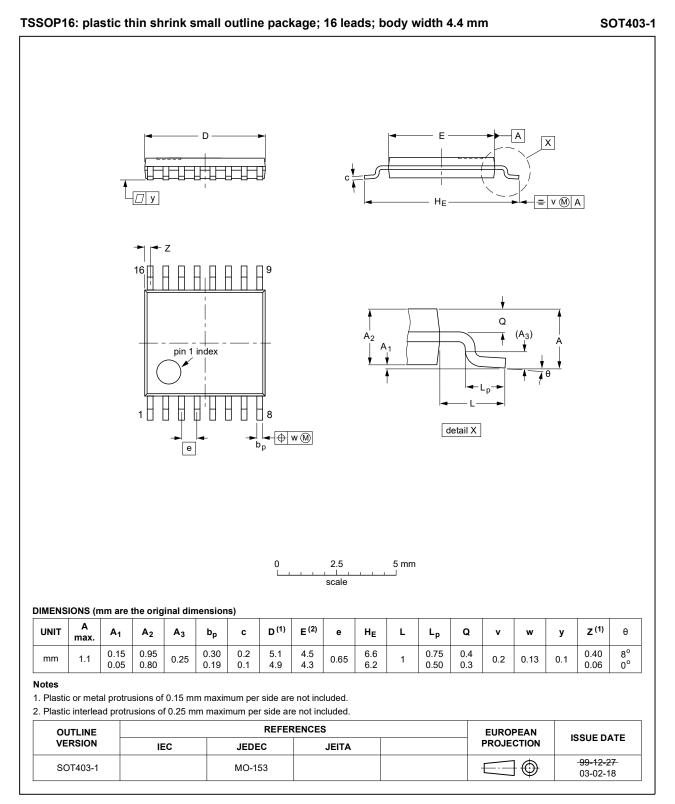


Fig. 14. Package outline SOT403-1 (TSSOP16)

#### 8-bit parallel-in/serial out shift register

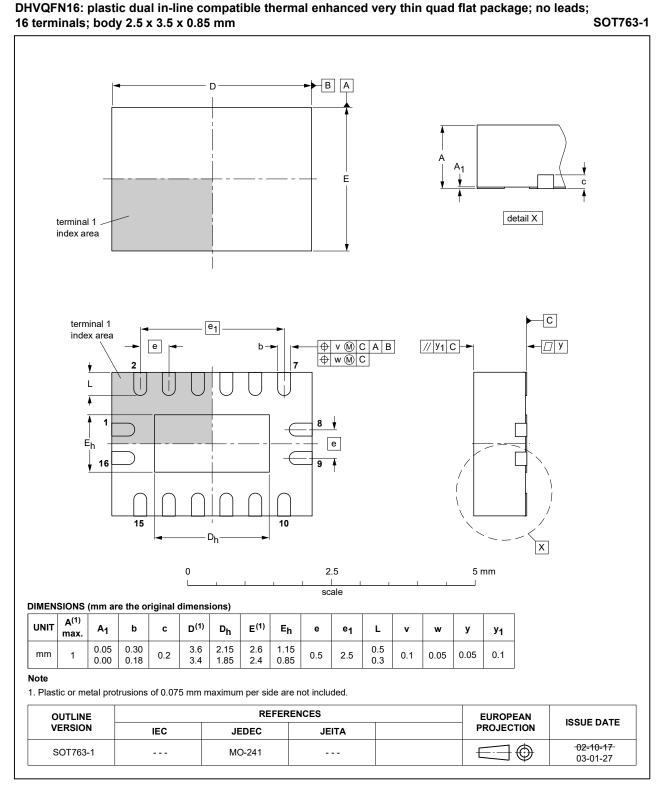


Fig. 15. Package outline SOT763-1 (DHVQFN16)

### 13. Abbreviations

Table 10. Abbreviations				
Acronym	Description			
CMOS	Complementary Metal-Oxide Semiconductor			
DUT	Device Under Test			
ESD	ElectroStatic Discharge			
HBM	Human Body Model			
MIL	Military			
MM	Machine Model			
TTL	Transistor-Transistor Logic			

### 14. Revision history

Table 11. Revision history						
Document ID	Release date	Data sheet status	Change notice	Supersedes		
74HC_HCT165_Q100 v.3	20200423	Product data sheet	-	74HC_HCT165_Q100 v.2		
Modifications:	<ul> <li><u>Section 2</u> updated.</li> <li><u>Table 4</u>: Derating values for P<sub>tot</sub> total power dissipation updated.</li> </ul>					
74HC_HCT165_Q100 v.2	20170821	Product data sheet	-	74HC_HCT165_Q100 v.1		
Modifications:	<ul> <li><u>Section 1</u> updated.</li> <li><u>Table 7</u>: Hold time for 74HC165 has been updated.</li> <li>The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> </ul>					
74HC_HCT165_Q100 v.1	20120717	Product data sheet	-	-		

### 15. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions".
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